Pb Free Product



NCE3080K

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE3080K uses advanced trench technology and design to provide excellent R_{DS(ON)} with low gate charge. It can be used in a wide variety of applications.

General Features

V_{DS} =30V,I_D =80A

 $R_{DS(ON)}$ <6.5m Ω @ V_{GS} =10V

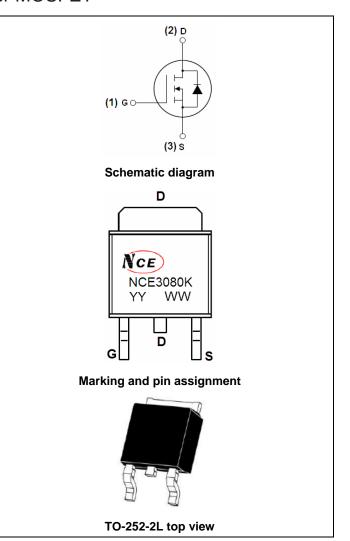
 $R_{DS(ON)}$ < 10m Ω @ V_{GS} =5V

- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE3080K	NCE3080K	TO-252-2L	-	-	-

Absolute Maximum Ratings (T_C=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	30	V
Gate-Source Voltage	V _G s	±20	V
Drain Current-Continuous	I _D	80	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	50	Α
Pulsed Drain Current	I _{DM}	170	Α
Maximum Power Dissipation	P _D	83	W
Derating factor		0.56	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	306	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C





NCE3080K

Thermal Characteristic

Thermal Resistance,Junction-to-Case ^(Note 2)	$R_{ heta JC}$	1.8	°C/W	
---	----------------	-----	------	--

Electrical Characteristics (T_C=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit	
Off Characteristics	•		•				
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA		-	-	V	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA	
On Characteristics (Note 3)	·						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_D=250\mu A$	1	1.6	3	V	
Drain-Source On-State Resistance	D	V _{GS} =10V, I _D =30A	-	5.5	6.5	mΩ	
Diain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =5V, I _D =24A	-	7.5	10		
Forward Transconductance	g fs	V _{DS} =5V,I _D =24A	20	-	-	S	
Dynamic Characteristics (Note4)	·						
Input Capacitance	C _{lss}	\/ -15\/\/ -0\/	-	2330	-	PF	
Output Capacitance	Coss	V_{DS} =15V, V_{GS} =0V, F=1.0MHz	-	460	-	PF	
Reverse Transfer Capacitance	C _{rss}	F=1.0WHZ	-	230	-	PF	
Switching Characteristics (Note 4)							
Turn-on Delay Time	t _{d(on)}		-	20	ı	nS	
Turn-on Rise Time	t _r	V_{DD} =10 V , I_{D} =30 A	-	15	ı	nS	
Turn-Off Delay Time	$t_{d(off)}$	V_{GS} =10 V , R_{GEN} =2.7 Ω	-	60	-	nS	
Turn-Off Fall Time	t _f		-	10	-	nS	
Total Gate Charge	Qg	V _{DS} =10V,I _D =30A,	-	51	-	nC	
Gate-Source Charge	Q_{gs}	$V_{\text{DS}} = 10V, I_{\text{D}} = 30A,$ $V_{\text{GS}} = 10V$	-	14	ı	nC	
Gate-Drain Charge	Q_{gd}	v _{GS} -10 v	-	11	-	nC	
Drain-Source Diode Characteristics							
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =24A	-	-	1.2	V	
Diode Forward Current (Note 2)	Is		-	-	80	Α	
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 80A	-	32	50	nS	
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	12	20	nC	
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)					

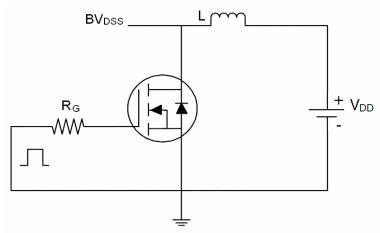
Notes:

- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature.}$
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- 3. Pulse Test: Pulse Width ≤ $300\mu s$, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production
- **5.** EAS condition: Tj=25 $^{\circ}\text{C}$,VDD=15V,VG=10V,L=0.5mH,Rg=25 Ω , IAS=35A

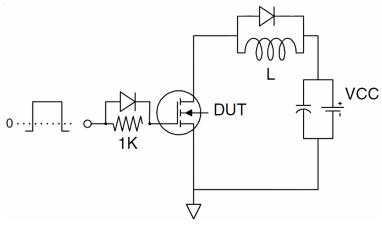


Test Circuit

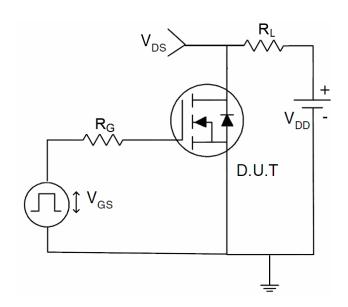
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit:



3) Switch Time Test Circuit:



Pb Free Product



NCE3080K

Typical Electrical and Thermal Characteristics (Curves)

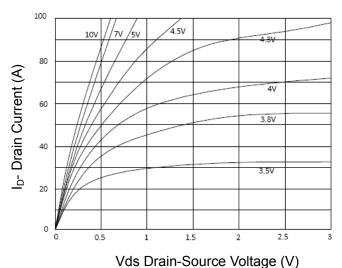


Figure 1 Output Characteristics

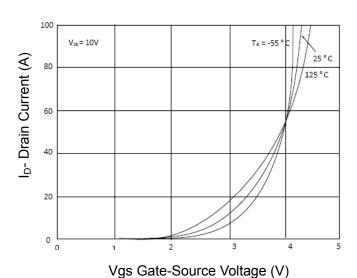


Figure 2 Transfer Characteristics

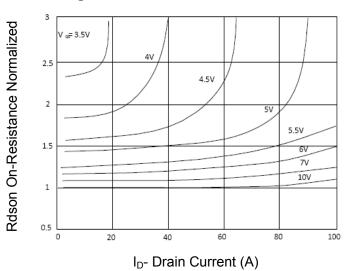


Figure 3 Rdson- Drain Current

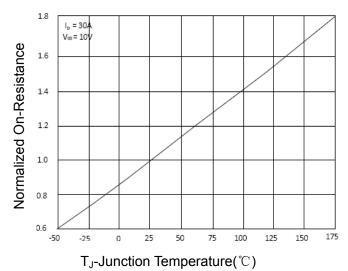


Figure 4 Rdson-JunctionTemperature

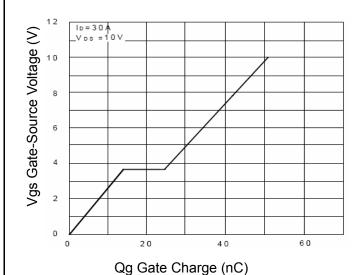


Figure 5 Gate Charge

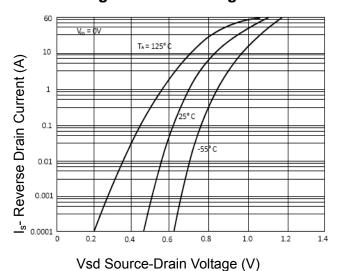
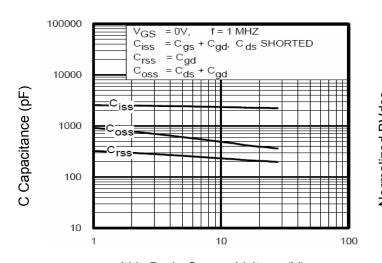


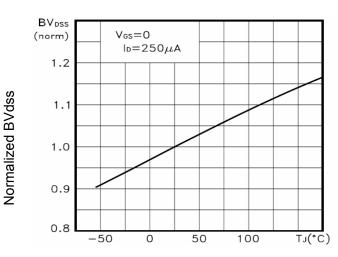
Figure 6 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

Figure 7 Capacitance vs Vds



 T_J -Junction Temperature (°C) Figure 9 BV_{DSS} vs Junction Temperature

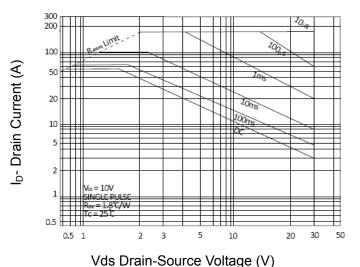
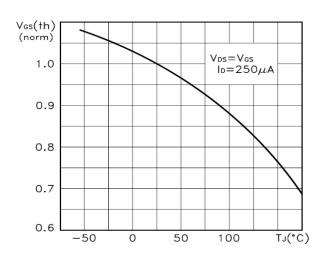
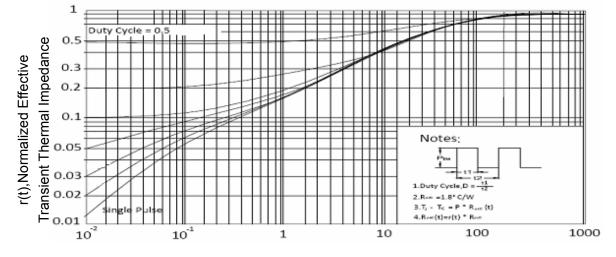


Figure 8 Safe Operation Area



 T_J -Junction Temperature(${}^{\circ}$ C)

Figure 10 V_{GS(th)} vs Junction Temperature



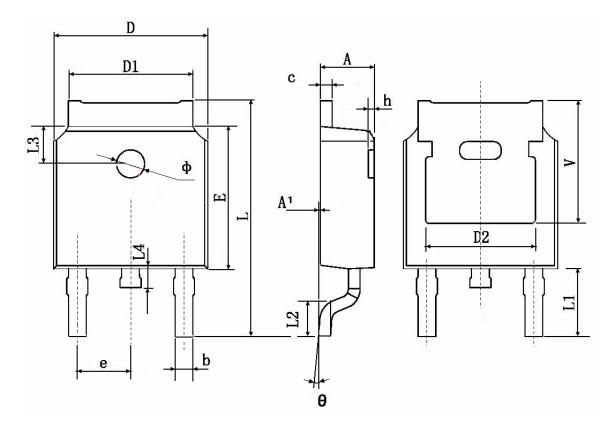
Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

Pb Free Product



TO-252 Package Information



Symbol	Dimensions I	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
Α	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.83	BO TYP.	0.190	0.190 TYP.		
Е	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.900 TYP.		0.114 TYP.			
L2	1.400	1.700	0.055	0.067		
L3	1.600	TYP.	0.063	0.063 TYP.		
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350	TYP.	0.211 TYP.			



http://www.ncepower.com

NCE3080K

Attention

- Any and all NCE power products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE power representative nearest you before using any NCE power products described or contained herein in such applications.
- NCE power assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE power products described or contained herein.
- Specifications of any and all NCE power products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE power products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE power believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE power product that you intend to use.
- This catalog provides information as of Sep.2010. Specifications and information herein are subject to change without notice.